

### Low Capacitance TVS Diode

- ESD / transient protection of high-speed data lines in 3.3 / 5 / 12 V applications according to: IEC61000-4-2 (ESD): up to ± 25 KV (contact) IEC61000-4-4 (EFT): 40 A (5/50 ns) IEC61000-4-5 (surge): up to 2.5 A (8/20 µs)
- Smallest form factor down to 1.0 x 0.6 x 0.4 mm
- Max. working voltage: -8 / +14 V or +8 / -14 V
- Ultra low dynamic resistance down to  $\textbf{0.3}~\boldsymbol{\Omega}$
- Very low capacitance down to 2 pF
- Very low reverse current < 1 nA typ.
- Very low series inductance down to 0.4 nH
- Pb-free (RoHS compliant) package

#### Applications

- USB 2.0, 10/100 Ethernet, Firewire, DVI
- Mobile communication
- Consumer products (STB, MP3, DVD, DSC...)
- LCD displays, camera
- Notebooks and destop computers, peripherals



ESD8V0L1B-02EL ESD8V0L1B-02LRH

#### ESD8V0L2B-03L

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Туре	Package	Configuration	Marking
ESD8V0L1B-02EL*	TSLP-2-18	1 channel, bi-directional	E7
ESD8V0L1B-02LRH	TSLP-2-17	1 channel, bi-directional	B3
ESD8V0L2B-03L	TSLP-3-1	2 channels, bi-directional	B3







**Maximum Ratings** at  $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit
ESD contact discharge <sup>1)</sup>	V <sub>ESD</sub>		kV
ESD8V0L1B		25	
ESD8V0L2B, between all pins		15	
Peak pulse current ( $t_p = 8 / 20 \ \mu s$ ) <sup>2)</sup>	I <sub>pp</sub>		A
ESD8V0L1B		2.5	
ESD8V0L2B		1	
Operating temperature range	T <sub>op</sub>	-55125	°C
Storage temperature	T <sub>stg</sub>	-65150	

 $^{1}V_{\text{ESD}}$  according to IEC61000-4-2

 $^{2}I_{pp}$  according to IEC61000-4-5



Parameter	Symbol		Values		Unit
			typ.	max.	
Characteristics	•				•
Reverse working voltage	V <sub>RWM</sub>	-8	-	14	V
Breakdown voltage	V <sub>(BR)</sub>				
<i>I</i> <sub>(BR)</sub> = 1 mA, from pin 2 to 1, ESD8V0L1B		14.5	-	-	
$I_{(BR)}$ = 1 mA, from pin 1 to 2, ESD8V0L1B		8.5	-	-	
$I_{(BR)}$ = 1 mA, from pin 1/2 to 3, ESD8V0L2B		14.5	-	-	
$I_{(BR)}$ = 1 mA, from pin 3 to 1/2, ESD8V0L2B		8.5	-	-	
$I_{(BR)}$ = 1 mA, from pin 1 to 2, ESD8V0L2B		23	-	-	
Reverse current	I <sub>R</sub>	-	< 1	50	nA
$V_{R}$ = 3 V, between all pins					
Clamping voltage (contact) <sup>1)</sup>	V <sub>CL</sub>				V
$V_{\text{ESD}}$ = +15 kV , from pin 1 to 2, ESD8V0L1B		-	21	-	
$V_{\text{ESD}}$ = -15 kV, from pin 1 to 2, ESD8V0L1B		-	16	-	
$V_{ESD}$ = +15 kV , from pin 1/2 to 3, ESD8V0L2B		-	26	-	
$V_{\text{ESD}}$ = -15 kV , from pin 1/2 to 3, ESD8V0L2B		-	20	-	
Line capacitance <sup>2)</sup>	CT				pF
<i>V</i> <sub>R</sub> = 0 V, <i>f</i> = 1 MHz, ESD8V0L1B		-	8.5	13	
<i>V</i> <sub>R</sub> = 0 V, <i>f</i> = 1 MHz, ESD8V0L2B,					
from pin 1/2 to 3		-	4	7	
from pin 1 to 2, pin 3 is not connected		-	2	4	
Dynamic resistance (tp=30ns)	R <sub>D</sub>				Ω
ESD8V0L1B		-	0.3	-	
ESD8V0L2B		-	0.6	-	

### **Electrical Characteristics** at $T_A = 25^{\circ}$ C, unless otherwise specified

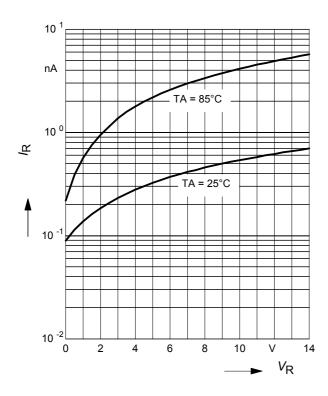
 $^{1}V_{\text{ESD}}$  according to IEC61000-4-2

<sup>2</sup>Total capacitance line to ground



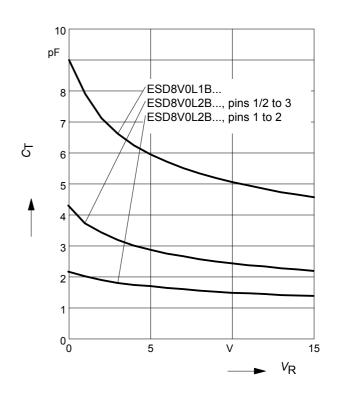
### **Reverse current** $I_{R} = f(V_{R})$

 $T_A$  = Parameter



# **Diode capacitance** $C_{T} = f(V_{R})$

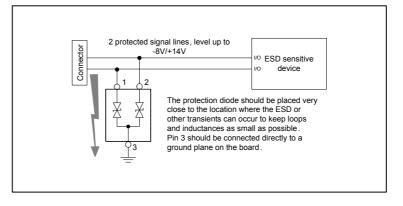
*f* = 1MHz





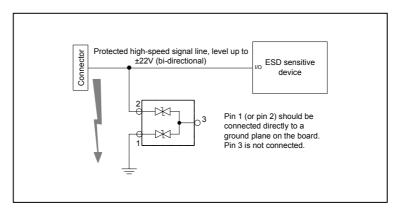
### Application example ESD8V0L2B...

2 channels, bi-directional



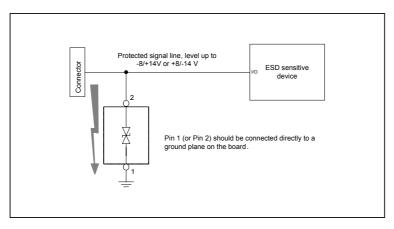
### Application example ESD8V0L2B...

1 high-speed channel, bi-directional

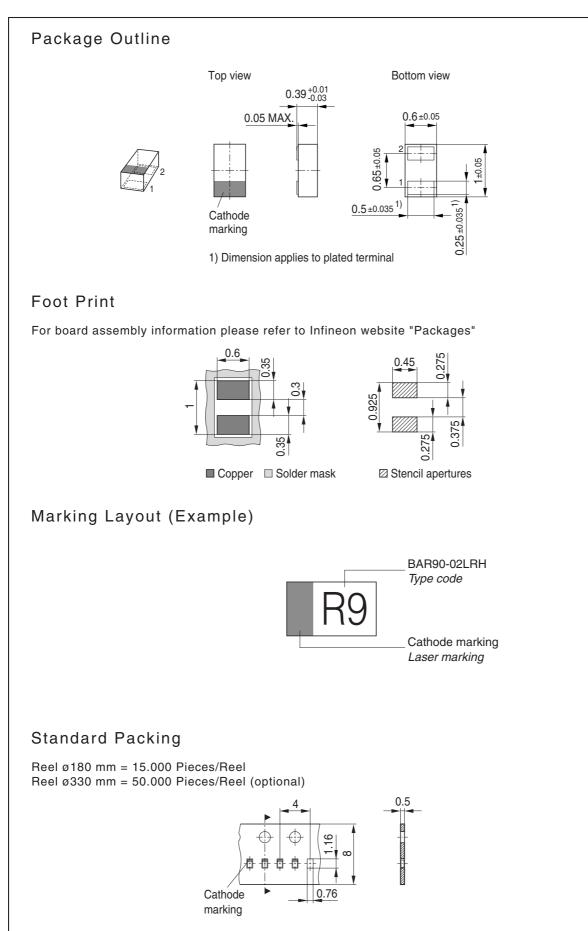


# Application example ESD8V0L1B...

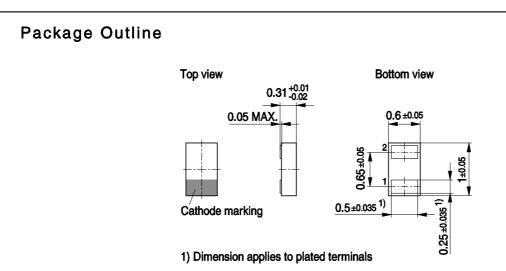
1 channel, bi-directional





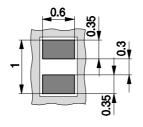


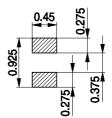




# Foot Print

For board assembly information please refer to Infineon website "Packages"

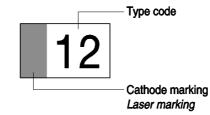




Copper Solder mask

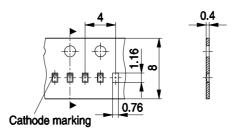
 $\ensuremath{\boxtimes}$  Stencil apertures

# Marking Layout



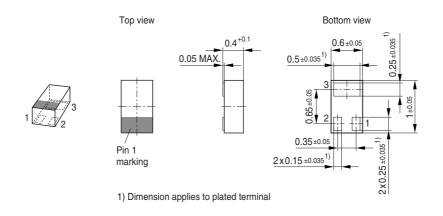
# Standard Packing

Reel ø330 mm = 15.000 Pieces/Reel



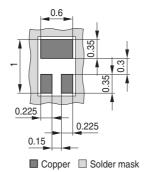


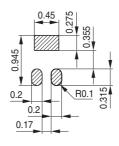




# Foot Print

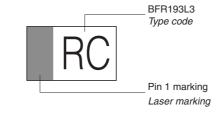
For board assembly information please refer to Infineon website "Packages"





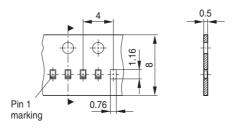
Stencil apertures

# Marking Layout (Example)



### Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel







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